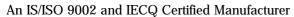


# Continental Device India Limited





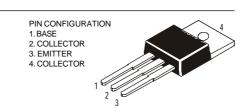
### **TO-220 Plastic Package**

CSC1398, CSC1398A

## CSC1398, CSC1398A Complementary CSA748

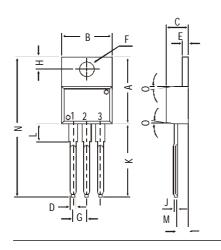
Medium Power Amplifier

NPN PLASTIC POWER TRANSISTORS



1000

10004



diminsions in mm.	DIM	MIN.	MAX.
	Α	14.42	16.51
	В	9.63	10.67
	С	3.56	4.83
	D		0.90
	Ε	1.15	1.40
	F	3.75	3.88
	G	2.29	2.79
	Н	2.54	3.43
	J		0.56
	K	12.70	14.73
	L	2.80	4.07
	М	2.03	2.92
	N		31.24
	0	DEG 7	

### ABSOLUTE MAXIMUM RATINGS

		1398	1398A	
Collector-base voltage (open emitter)	$V_{CBO}$	max.	70 V	
Collector-emitter voltage (open base)	$V_{C\!E\!O}$	max. 50	70 V	
Collector current	$I_C$	max.	2 A	
Total power dissipation up to $T_C = 25^{\circ}C$	$P_{tot}$	max.	15 W	
Junction temperature	$T_j$	max.	<i>150</i> ℃	
Collector-emitter saturation voltage	•			
$I_C = 2 A; I_B = 200 mA$	$V_{CEsat}$	max.	1.0 V	
D.C. current gain				
$I_C = 1 A$ ; $V_{CE} = 5 V$	$h_{\!F\!E}$	min. 50	<i>50</i>	
		max. 220	160	

## **RATINGS** (at $T_A$ =25°C unless otherwise specified)

Limiting values		1398	13	98A	
Collector-base voltage (open emitter)	$V_{CBO}$	max.	70	,	V
Collector-emitter voltage (open base)	$V_{C\!E\!O}$	max. 50		70	V
Emitter-base voltage (open collector)	$V_{EBO}$	max.	5.0	,	V

Collector current	$I_C$	max.	2	$\boldsymbol{A}$
Collector current (Peak value)	$I_{CP}$	max.	3	$\boldsymbol{A}$
Total power dissipation up to $T_C = 25^{\circ}C$	$P_{tot}$	max.	15	W
Junction temperature	$T_j$	max.	<i>150</i>	${\mathscr C}$
Storage temperature	$T_{stg}$	$-\ell$	35 to +13	50 C
CHARACTERISTICS				
$T_{amb} = 25$ °C unless otherwise specified				
Taill) 20 0 diness outerwise specified		1398	398 1398A	
Collector cutoff current				
$I_E = 0$ ; $V_{CB} = 40 \text{ V}$	$I_{CBO}$	max.	1	$\mu A$
$I_{B} = 0$ ; $V_{CF} = 20 \text{ V}$	$I_{CEO}$	max.	100	$\mu A$
Emitter cut-off current	CEC			•
$I_C = 0; V_{EB} = 5 V$	$I_{EBO}$	max.	100	$\mu A$
Breakdown voltages	220			•
$I_C = 10 \text{ mA}; I_B = 0$	$V_{C\!E\!O}$	min. 50		70 V
$I_C = 1 \text{ mA}; I_E = 0$	$V_{CBO}$	min.	70	V
$I_E = 1 \text{ mA}; I_C = 0$	$V_{EBO}$	min.	5.0	V
Saturation voltages				
$I_C = 2 A; I_B = 200 mA$	$V_{CEsat}$	max.	1.0	V
$I_C = 2 A; I_B = 200 mA$	$V_{BEsat}$	max.	1.5	V
D.C. current gain				
$I_C = 100 \text{ mA}; V_{CE} = 5 \text{ V}$	$h_{\!F\!E}$	min.	30	
$I_C = 1 A; V_{CE} = 5 V^{**}$	$h_{\!F\!F}$	min. 50		50
C	12	max. 220	1	60
** h <sub>FE</sub> classification:		1398A P: 50-100 Q: 80-160		

#### **Notes**

#### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290
e-mail sales@cdil.com www.cdil.com